# NSN 5962-01-214-8670

Memory Microcircuit - Page 1 of 1



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# **Body Length:**

Between 1.045 inches and 1.110 inches

# **Body Width:**

0.405 inches

# **Body Height:**

0.205 inches

## **Operating Tempurature Range:**

-55.0/+125.0 degrees celsius

#### Storage Tempurature Range:

-65.0/+150.0 degrees celsius

#### **End Application:**

Radar set an/fps-115

# **Features Provided:**

Hermetically sealed and burn in and programmable and w/enable and schottky and high impedance

#### Inclosure Material:

Ceramic

#### Inclosure Configuration:

Dual-in-line

# **Output Logic Form:**

Transistor-transistor logic

# Input Circuit Pattern:

12 input

## **Terminal Surface Treatment:**

Solder

# Voltage Rating And Type Per Characteristic:

-0.5 volts power source and 7.0 volts power source

# **Time Rating Per Chacteristic:**

Err-060 hand pull and err-060 hand

# Memory Device Type:

Rom

# **Test Data Document:**

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

#### **Terminal Type And Quantity:**

22 printed circuit

#### Shelf Life:

N/a

# Unit Of Measure:

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# Demilitarization:

Yes - demil/mli

# Fiig:

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